## NSN 5961-01-462-1881

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Inclosure Material:
Ceramic
Overall Length:
Between 1.450 inches and 1.730 inches
Overall Height:
Between 0.144 inches and 0.164 inches
Overall Width:
Between 0.172 inches and 0.192 inches
End Application:
Otps, hybrid/i e/i fscm 26512
Mounting Method:
Terminal
Semiconductor Material:
Germanium
Voltage Rating In Volts Per Characteristic:
100.0 peak-point voltage
Special Features:
Temperature range minus 40 degrees to positive 75 degrees celsius
Terminal Type And Quantity:
2 insulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
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